

# Ultra Low Power, 128/64/32/16 kB, LCD MCU with Integrated 240-960 MHz EZRadioPRO® Transceiver

#### Ultra-Low Power @ 3.6 V

- 110 μA/MHz IBAT; DC-DC enabled
- 110 nA sleep current with data retention; POR monitor enabled
- 400 nA sleep current with smaRTClock (internal LFO)
- 700 nA sleep current with smaRTClock (external XTAL)
- 2 μs wake-up from any sleep mode

#### 12-Bit; 16 ch. Analog to Digital Converter

- Up to 75 ksps 12-bit mode or 300 ksps 10-bit mode
- External pin or internal VREF (no external capacitor required)
- On-chip PGA allows measuring voltages up to twice the reference voltage
- Autonomous burst mode with 16-bit automatic averaging accumulator
- Integrated temperature sensor

#### **Two Low Current Comparators**

- Programmable hysteresis and response time
- Configurable as interrupt or reset source

#### **Internal 6-Bit Current Reference**

- Up to ±500 μA; source and sink capability
- Enhanced resolution via PWM interpolation

#### Integrated LCD Controller

- Supports up to 128 segments (32x4)
- Integrated charge pump for contrast control

#### **Metering-Specific Peripherals**

- DC-DC buck converter allows dynamic voltage scaling for maximum efficiency (250 mW output)
- Sleep-mode pulse accumulator with programmable switch de-bounce and pull-up control interfaces directly to metering sensor
- Dedicated Packet Processing Engine (DPPE) includes hardware AES, DMA, CRC, and encoding blocks for acceleration of wireless protocols
- Manchester and 3 out of 6 encoder hardware for power efficient implementation of the wireless M-bus specification

### EZRadioPRO® Transceiver

- Frequency range = 240–960 MHz
- Sensitivity = -121 dBm
- FSK, GFSK, and OOK modulation
- Max output power = +20 dBm (Si1020/1/2/3), +13 dBm (Si1024/25/26/27)

- RF power consumption
  - 18.5 mA receive
  - 18 mA @ +1 dBm transmit
  - 30 mA @ +13 dBm transmit
  - 85 mA @ +20 dBm transmit
  - Data rate = 0.123 to 256 kbps
  - Auto-frequency calibration (AFC)
  - Antenna diversity and transmit/receive switch control
  - Programmable packet handler
  - TX and RX 64-byte FIFOs
  - Frequency hopping capability
  - On-chip crystal tuning

#### High-Speed 8051 µC Core

 Pipelined instruction architecture; executes 70% of instructions in 1 or 2 system clocks

#### Memory

- Up to 128 kB Flash; In-system programmable; Full read/write/erase functionality over the entire supply range
- Up to 8 kB data retention RAM

#### **Digital Peripherals**

- 53 port I/O; All 5 V tolerant with high sink current and programmable drive strength
- Hardware SMBus<sup>™</sup> (I2C<sup>™</sup> compatible), 2 x SPI<sup>™</sup>, and UART serial ports available concurrently
- Four general-purpose 16-bit counter/timers
- Programmable 16-bit counter/timer array with six capture/compare modules and watchdog timer

#### Clock Sources

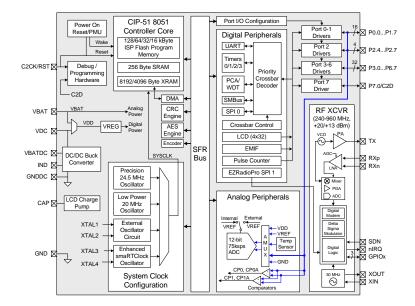
- Precision internal oscillators: 24.5 MHz with ±2% accuracy supports UART operation; spread-spectrum mode for reduced EMI
- Low power internal oscillator: 20 MHz
- External oscillator: Crystal, RC, C, CMOS clock
- smaRTClock oscillator: 32.768 kHz crystal or 16.4 kHz internal LFO with three independent alarms

#### **On-Chip Debug**

- On-chip debug circuitry facilitates full speed, non-intrusive in-system debug (no emulator required)
- Provides 4 breakpoints, single stepping

#### **Packages**

- -85 pin LGA (6 x 8 mm)





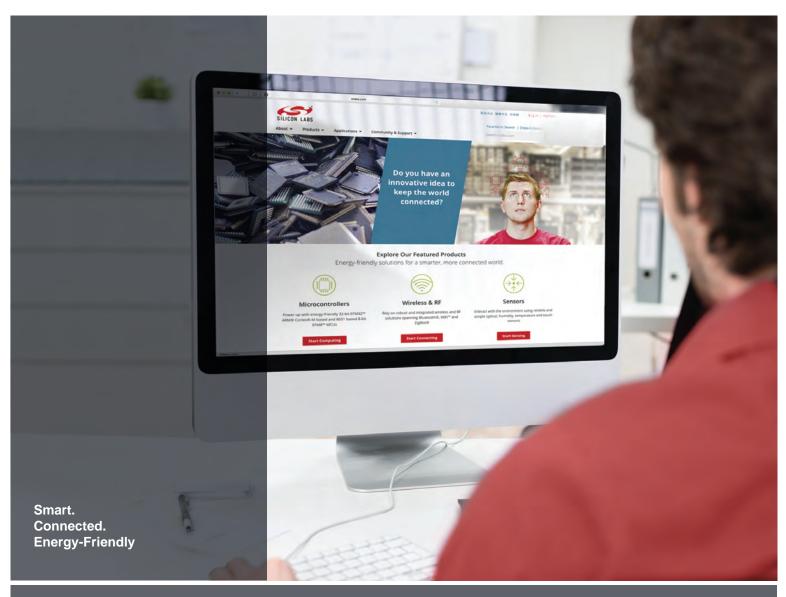
# Ultra Low Power, 128/64/32/16 kB, LCD MCU with Integrated 240-960 MHz EZRadioPRO® Transceiver

# **Selected Electrical Specifications**

Parameter	Symbol	Conditions	Min	Тур	Max	Units
Active mode current	IBAT	VBAT = 3.6 V, F = 20 MHz	_	110	_	μA/MHz
Active mode current	IBAT	F = 20 MHz LFO; DC-DC enabled executing code from FLASH; PCLKACT=0x00; VBAT=3.6V	_	2.2	_	mA
Sleep mode current	IDD	Sleep Mode, SmaRTClock running, internal LFO; 3.6 V	_	0.4	_	μΑ
Sleep mode current	IDD	Sleep Mode, SmaRTClock running, 32.768 kHz crystal; 3.6 V	_	0.7		μА
Buck regulator efficiency		3.6 V input voltage	_	80	_	%
LCD refresh current 1		Internal LFO, LCD charge pump disabled; 60 Hz; non- multiplexed operation (static mode); 3.6 V	_	0.4	_	μА
LCD refresh current 2		Internal LFO, LCD charge pump disabled; 60 Hz; multi- plexed operation; 3.6 V	_	0.8	_	μА
Supply input voltage	VBAT		1.8	3.6	3.8	V

# **Product Family**

Part Number	Memory (Flash/ RAM)	TX Output Power (dBm)	I/O	LCD	Package (mm)
Si1020-B-GM3	128 kB/8 kB	20	53	32x4	LGA85 (6x8)
Si1021-B-GM3	64 kB/8 kB	20	53	32x4	LGA85 (6x8)
Si1022-B-GM3	32 kB/8 kB	20	53	32x4	LGA85 (6x8)
Si1023-B-GM3	16 kB/4 kB	20	53	32x4	LGA85 (6x8)
Si1024-B-GM3	128 kB/8 kB	13	53	32x4	LGA85 (6x8)
Si1025-B-GM3	64 kB/8 kB	13	53	32x4	LGA85 (6x8)
Si1026-B-GM3	32 kB/8 kB	13	53	32x4	LGA85 (6x8)
Si1027-B-GM3	16 kB/4 kB	13	53	32x4	LGA85 (6x8)









#### Disclaimer

Silicon Laboratories intends to provide customers with the latest, accurate, and in-depth documentation of all peripherals and modules available for system and software implementers using or intending to use the Silicon Laboratories products. Characterization data, available modules and peripherals, memory sizes and memory addresses refer to each specific device, and "Typical" parameters provided can and do vary in different applications. Application examples described herein are for illustrative purposes only. Silicon Laboratories reserves the right to make changes without further notice and limitation to product information, specifications, and descriptions herein, and does not give warranties as to the accuracy or completeness of the included information. Silicon Laboratories shall have no liability for the consequences of use of the information supplied herein. This document does not imply or express copyright licenses granted hereunder to design or fabricate any integrated circuits. The products must not be used within any Life Support System without the specific written consent of Silicon Laboratories. A "Life Support System" is any product or system intended to support or sustain life and/or health, which, if it fails, can be reasonably expected to result in significant personal injury or death. Silicon Laboratories products are generally not intended for military applications. Silicon Laboratories products shall under no circumstances be used in weapons of mass destruction including (but not limited to) nuclear, biological or chemical weapons, or missiles capable of delivering such weapons.

#### **Trademark Information**

Silicon Laboratories Inc., Silicon Laboratories, Silicon Labs, SiLabs and the Silicon Labs logo, CMEMS®, EFM, EFM32, EFR, Energy Micro, Energy Micro logo and combinations thereof, "the world's most energy friendly microcontrollers", Ember®, EZLink®, EZMac®, EZRadio®, EZRadioPRO®, DSPLL®, ISOmodem ®, Precision32®, ProSLIC®, SiPHY®, USBXpress® and others are trademarks or registered trademarks of Silicon Laboratories Inc. ARM, CORTEX, Cortex-M3 and THUMB are trademarks or registered trademarks of ARM Holdings. Keil is a registered trademark of ARM Limited. All other products or brand names mentioned herein are trademarks of their respective holders.



Silicon Laboratories Inc. 400 West Cesar Chavez Austin, TX 78701 USA